NSN 5961-00-052-4115

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View Online at https://aerobasegroup.com/nsn/5961-00-052-4115 **Inclosure Material:** Metal **Overall Length:** 0.562 inches **Overall Height:** 0.562 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 55.0 collector to emitter voltage/static/base open and 100.0 collector to emitter voltage, dc with specified circuit between base and emitter and 10.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 3.00 amperes source cutoff current and 6.00 amperes source cutoff current **Power Rating Per Characteristic:**

75.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Specification Data:

81349-mil-s-19500/208 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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